8-bit serial-in, parallel-out shift register Rev. 1 — 16 August 2013

Product data sheet

1. General description

The 74HC164-Q100; 74HCT164-Q100 is an 8-bit serial-in/parallel-out shift register. The device features two serial data inputs (DSA and DSB), eight parallel data outputs (Q0 to Q7). Data is entered serially through DSA or DSB and either input can be used as an active HIGH enable for data entry through the other input. Data is shifted on the LOW-to-HIGH transitions of the clock (CP) input. A LOW on the master reset input (MR) clears the register and forces all outputs LOW, independently of other inputs. Inputs include clamp diodes that enable the use of current limiting resistors to interface inputs to voltages in excess of V_{CC} .

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - Specified from –40 °C to +85 °C and from –40 °C to +125 °C
- Input levels:
 - ◆ For 74HC164-Q100: CMOS level
 - ◆ For 74HCT164-Q100: TTL level
- Gated serial data inputs
- Asynchronous master reset
- Complies with JEDEC standard no. 7A
- ESD protection:
 - MIL-STD-883, method 3015 exceeds 2000 V
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)
- Multiple package options

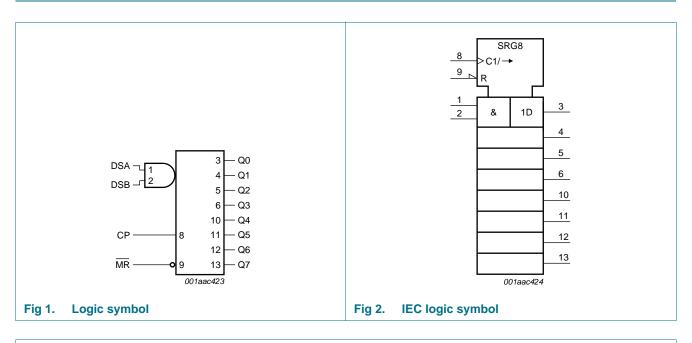
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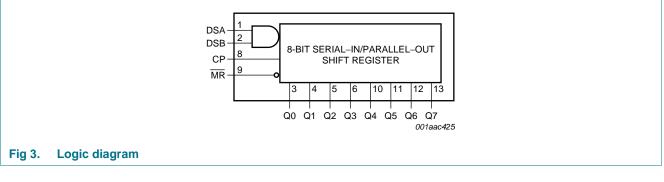
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3. Ordering information

Table 1.OrderingType number	information Package				
	Temperature range	Name	Description	Version	
74HC164D-Q100	–40 °C to +125 °C	SO14	plastic small outline package; 14 leads; body	SOT108-1	
74HCT164D-Q100			width 3.9 mm		
74HC164PW-Q100	–40 °C to +125 °C	TSSOP14	plastic thin shrink small outline package;	SOT402-1	
74HCT164PW-Q100			14 leads; body width 4.4 mm		
74HC164BQ-Q100	–40 °C to +125 °C	DHVQFN14	plastic dual in-line compatible thermal enhanced	SOT762-1	
74HCT164BQ-Q100			very thin quad flat package; no leads; 14 terminals; body $2.5 \times 3 \times 0.85$ mm		

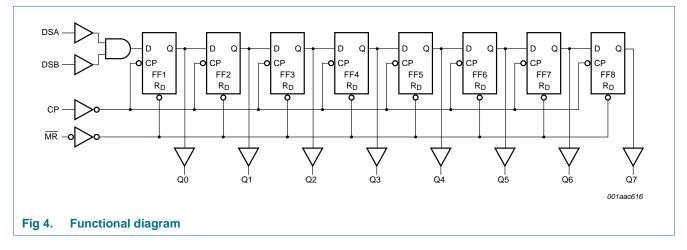
4. Functional diagram



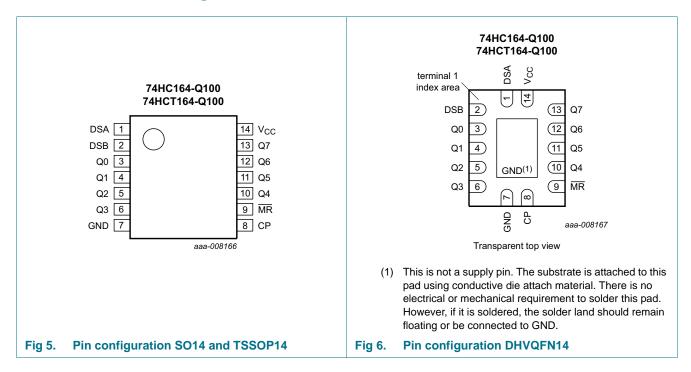


74HC164-Q100; 74HCT164-Q100

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5. Pinning information



5.1 Pinning

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5.2 Pin description

Table 2.	Pin description	
Symbol	Pin	Description
DSA	1	data input
DSB	2	data input
Q0 to Q7	3, 4, 5, 6, 10, 11, 12, 13	output
GND	7	ground (0 V)
СР	8	clock input (LOW-to-HIGH, edge-triggered)
MR	9	master reset input (active LOW)
V _{CC}	14	positive supply voltage

6. Functional description

Table 3. Function table^[1]

Operating	Input		Output	Output		
modes	MR	СР	DSA	DSB	Q0	Q1 to Q7
Reset (clear)	L	x	x	X	L	L to L
Shift	Н	\uparrow	I	I	L	q0 to q6
	Н	\uparrow	I	h	L	q0 to q6
	Н	\uparrow	h	I	L	q0 to q6
	Н	\uparrow	h	h	Н	q0 to q6

[1] H = HIGH voltage level

h = HIGH voltage level one set-up time prior to the LOW-to-HIGH clock transition

L = LOW voltage level

I = LOW voltage level one set-up time prior to the LOW-to-HIGH clock transition

q = lower case letters indicate the state of the referenced input one set-up time prior to the LOW-to-HIGH clock transition

 \uparrow = LOW-to-HIGH clock transition

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Limiting values 7.

Table 4. **Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+7	V
I _{IK}	input clamping current	$V_{\rm I} < -0.5$ V or $V_{\rm I} > V_{\rm CC}$ + 0.5 V	<u>[1]</u> _	±20	mA
I _{OK}	output clamping current	$V_{\rm O}$ < –0.5 V or $V_{\rm O}$ > $V_{\rm CC}$ + 0.5 V	<u>[1]</u> _	±20	mA
lo	output current	$-0.5 \text{ V} < \text{V}_{\text{O}} < \text{V}_{\text{CC}} + 0.5 \text{ V}$	-	±25	mA
I _{CC}	supply current		-	50	mA
I _{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation		[2] _	500	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SO14 package: Ptot derates linearly with 8 mW/K above 70 °C.

For TSSOP14 packages: Ptot derates linearly with 5.5 mW/K above 60 °C. For DHVQFN14 packages: Ptot derates linearly with 4.5 mW/K above 60 °C.

Recommended operating conditions 8.

Table 5. **Recommended operating conditions**

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	74HC	164-Q10	D	74HC	T164-Q1	00	Unit
			Min	Тур	Max	Min	Тур	Max	
V _{CC}	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V _{CC}	0	-	V _{CC}	V
Vo	output voltage		0	-	V _{CC}	0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C
$\Delta t / \Delta V$	input transition rise and fall rate	$V_{CC} = 2.0 V$	-	-	625	-	-	-	ns/V
		$V_{CC} = 4.5 V$	-	1.67	139	-	1.67	139	ns/V
		$V_{CC} = 6.0 V$	-	-	83	-	-	-	ns/V

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9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		–40 °C t	o +85 °C	–40 °C to +125 °C		Unit	
			Min	Тур	Max	Min	Мах	Min	Max		
74HC16	4-Q100						1			1	
VIH	HIGH-level	$V_{CC} = 2.0 V$	1.5	1.2	-	1.5	-	1.5	-	V	
	input voltage	$V_{CC} = 4.5 V$	3.15	2.4	-	3.15	-	3.15	-	V	
		$V_{CC} = 6.0 V$	4.2	3.2	-	4.2	-	4.2	-	V	
V _{IL}	LOW-level	$V_{CC} = 2.0 V$	-	0.8	0.5	-	0.5	-	0.5	V	
	input voltage	$V_{CC} = 4.5 V$	-	2.1	1.35	-	1.35	-	1.35	V	
		$V_{CC} = 6.0 V$	-	2.8	1.8	-	1.8	-	1.8	V	
V _{OH}	HIGH-level	$V_{I} = V_{IH} \text{ or } V_{IL}$									
	output voltage	$I_0 = -20 \ \mu A; \ V_{CC} = 2.0 \ V$	1.9	2.0	-	1.9	-	1.9	-	V	
		$I_O = -20 \ \mu\text{A}; \ V_{CC} = 4.5 \ \text{V}$	4.4	4.5	-	4.4	-	4.4	-	V	
		$I_0 = -20 \ \mu A; \ V_{CC} = 6.0 \ V$	5.9	6.0	-	5.9	-	5.9	-	V	
		I_{O} = -4.0 mA; V_{CC} = 4.5 V	3.98	4.32	-	3.84	-	3.7	-	V	
		I_{O} = -5.2 mA; V_{CC} = 6.0 V	5.48	5.81	-	5.34	-	5.2	-	V	
V _{OL}	LOW-level	$V_{I} = V_{IH} \text{ or } V_{IL}$									
	output voltage	$I_0 = 20 \ \mu A; V_{CC} = 2.0 \ V$	-	0	0.1	-	0.1	-	0.1	V	
		$I_0 = 20 \ \mu A; V_{CC} = 4.5 \ V$	-	0	0.1	-	0.1	-	0.1	V	
		$I_0 = 20 \ \mu A; V_{CC} = 6.0 \ V$	-	0	0.1	-	0.1	-	0.1	V	
		I_{O} = 4.0 mA; V_{CC} = 4.5 V	-	0.15	0.26	-	0.33	-	0.4	V	
		$I_0 = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	0.16	0.26	-	0.33	-	0.4	V	
I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 V$	-	-	±0.1	-	±1	-	±1	μA	
l _{cc}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0$ V	-	-	8.0	-	80	-	160	μA	
CI	input capacitance		-	3.5	-	-	-	-	-	pF	
74HCT1	64-Q100										
V _{IH}	HIGH-level input voltage	V_{CC} = 4.5 V to 5.5 V	2.0	1.6	-	2.0	-	2.0	-	V	
V _{IL}	LOW-level input voltage	V_{CC} = 4.5 V to 5.5 V	-	1.2	0.8	-	0.8	-	0.8	V	
V _{он}	HIGH-level	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$									
	output voltage	I _O = -20 μA	4.4	4.5	-	4.4	-	4.4	-	V	
		I _O = -4.0 mA	3.98	4.32	-	3.84	-	3.7	-	V	
V _{OL}	LOW-level	$V_{I} = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 V$									
	output voltage	$I_0 = 20 \ \mu A; V_{CC} = 4.5 \ V$	-	0	0.1	-	0.1	-	0.1	V	
		$I_0 = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	0.15	0.26	-	0.33	-	0.4	V	
I	input leakage current	$V_{I} = V_{CC} \text{ or GND};$ $V_{CC} = 6.0 \text{ V}$	-	-	±0.1	-	±1	-	±1	μA	

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Table 6. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		–40 °C t	o +85 °C	–40 °C to	+125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
I _{CC}	supply current		-	-	8	-	80	-	160	μA
ΔI _{CC}	additional supply current	per input pin; $V_I = V_{CC} - 2.1 \text{ V}; I_O = 0 \text{ A};$ other inputs at V_{CC} or GND; $V_{CC} = 4.5 \text{ V}$ to 5.5 V	-	100	360	-	450	-	490	μΑ
CI	input capacitance		-	3.5	-	-	-	-	-	pF

10. Dynamic characteristics

Table 7. Dynamic characteristics

GND = 0 V; $t_r = t_f = 6$ ns; $C_L = 50$ pF; test circuit, see <u>Figure 10</u>; unless otherwise specified

Symbol	Parameter	Conditions			25 °C		–40 °C t	o +85 °C	–40 °C to	+125 °C	Unit
			Ν	Min	Тур	Max	Min	Max	Min	Max	-
74HC164	1-Q100										
t _{pd}	propagation	CP to Qn; see Figure 7	<u>[1]</u>								
	delay	$V_{CC} = 2.0 V$		-	41	170	-	215	-	255	ns
		$V_{CC} = 4.5 V$		-	15	34	-	43	-	51	ns
		$V_{CC} = 5.0 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$		-	12	-	-	-	-	-	ns
		$V_{CC} = 6.0 V$		-	12	29	-	37	-	43	ns
t _{PHL}	HIGH to LOW	MR to Qn; see Figure 8									
	propagation delay	$V_{CC} = 2.0 V$		-	39	140	-	175	-	210	ns
	delay	$V_{CC} = 4.5 V$		-	14	28	-	35	-	42	ns
		$V_{CC} = 5.0 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$		-	11	-	-	-	-	-	ns
		$V_{CC} = 6.0 V$		-	11	24	-	30	-	36	ns
t _t	transition time	see Figure 7	[2]								
		$V_{CC} = 2.0 V$		-	19	75	-	95	-	110	ns
		$V_{CC} = 4.5 V$		-	7	15	-	19	-	22	ns
		$V_{CC} = 6.0 V$		-	6	13	-	16	-	19	ns
t _W	pulse width	CP HIGH or LOW; see <u>Figure 7</u>									
		$V_{CC} = 2.0 V$	ł	80	14	-	100	-	120	-	ns
		$V_{CC} = 4.5 V$		16	5	-	20	-	24	-	ns
		$V_{CC} = 6.0 V$		14	4	-	17	-	20	-	ns
		MR LOW; see Figure 8									
		$V_{CC} = 2.0 V$	(60	17	-	75	-	90	-	ns
		$V_{CC} = 4.5 V$		12	6	-	15	-	18	-	ns
		$V_{CC} = 6.0 V$		10	5	-	13	-	15	-	ns

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Symbol	Parameter	Conditions		25 °C		–40 °C to	+85 °C	–40 °C to	o +125 °C	Uni
			Min	Тур	Max	Min	Max	Min	Max	
rec	recovery time	MR to CP; see Figure 8								
		V _{CC} = 2.0 V	60	17	-	75	-	90	-	ns
		V _{CC} = 4.5 V	12	6	-	15	-	18	-	ns
		V _{CC} = 6.0 V	10	5	-	13	-	15	-	ns
su	set-up time	DSA, and DSB to CP; see Figure 9								
		V _{CC} = 2.0 V	60	8	-	75	-	90	-	ns
		V _{CC} = 4.5 V	12	3	-	15	-	18	-	ns
		V _{CC} = 6.0 V	10	2	-	13	-	15	-	ns
ĥ	hold time	DSA, and DSB to CP; see <u>Figure 9</u>								
		V _{CC} = 2.0 V	+4	-6	-	4	-	4	-	ns
		V _{CC} = 4.5 V	+4	-2	-	4	-	4	-	ns
		$V_{CC} = 6.0 V$	+4	-2	-	4	-	4	-	ns
max	maximum	for Cp, see Figure 7								
	frequency	V _{CC} = 2.0 V	6	23	-	5	-	4	-	MH
		V _{CC} = 4.5 V	30	71	-	24	-	20	-	MH
	$V_{CC} = 5.0 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$	-	78	-	-	-	-	-	MH	
		$V_{CC} = 6.0 V$	35	85	-	28	-	24	-	MH
C _{PD}	power dissipation capacitance	per package; E V _I = GND to V _{CC}	<u>3]</u>	40	-	-	-	-	-	pF
74HCT10	64-Q100									
pd	propagation	CP to Qn; see Figure 7	1]							
	delay	$V_{CC} = 4.5 V$	-	17	36	-	45	-	54	ns
		V_{CC} = 5.0 V; C _L = 15 pF	-	14	-	-	-	-	-	ns
PHL	HIGH to LOW	MR to Qn; see Figure 8								
	propagation	$V_{CC} = 4.5 V$	-	19	38	-	48	-	57	ns
	delay	$V_{CC} = 5.0 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$	-	16	-	-	-	-	-	ns
t	transition time	see Figure 7	2]							
		$V_{CC} = 4.5 V$	-	7	15	-	19	-	22	ns
W	pulse width	CP HIGH or LOW; see <u>Figure 7</u>								
		$V_{CC} = 4.5 V$	18	7	-	23	-	27	-	ns
		MR LOW; see Figure 8								
		$V_{CC} = 4.5 V$	18	10	-	23	-	27	-	ns
rec	recovery time	MR to CP; see Figure 8								
		$V_{CC} = 4.5 V$	16	7	-	20	-	24	-	ns
su	set-up time	DSA, and DSB to CP; see <u>Figure 9</u>								
		$V_{CC} = 4.5 V$	12	6	-	15	-	18	-	ns

Dynamic characteristics ... continued Table 7.

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Symbol	Parameter	Conditions	25		25 °C -		–40 °C to +85 °C		–40 °C to +125 °C		Unit
			N	Min	Тур	Max	Min	Max	Min	Max	
t _h	hold time	DSA, and DSB to CP; see <u>Figure 9</u>						1		'	
		$V_{CC} = 4.5 V$		+4	-2	-	4	-	4	-	ns
f _{max}	maximum	for Cp, see Figure 7									
	frequency	$V_{CC} = 4.5 V$		27	55	-	22	-	18	-	MHz
		$V_{CC} = 5.0 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$		-	61	-	-	-	-	-	MHz
C _{PD}	power dissipation capacitance	per package; V _I = GND to V _{CC} – 1.5 V	<u>[3]</u>	-	40	-	-	-	-	-	pF

Table 7. Dynamic characteristics ...continued

 $GND = 0 \text{ V}; t_r = t_f = 6 \text{ ns}; C_L = 50 \text{ pF}; \text{ test circuit, see Figure 10}; unless otherwise specified$

 $\label{eq:tpd} [1] \quad t_{pd} \text{ is the same as } t_{PHL} \text{ and } t_{PLH}.$

$\label{eq:ttilde} [2] \quad t_t \text{ is the same as } t_{THL} \text{ and } t_{TLH}.$

[3] C_{PD} is used to determine the dynamic power dissipation (P_D in μW):

 $P_{D} = C_{PD} \times V_{CC}^{2} \times f_{i} \times N + \sum (C_{L} \times V_{CC}^{2} \times f_{o}) \text{ where:}$

 f_i = input frequency in MHz;

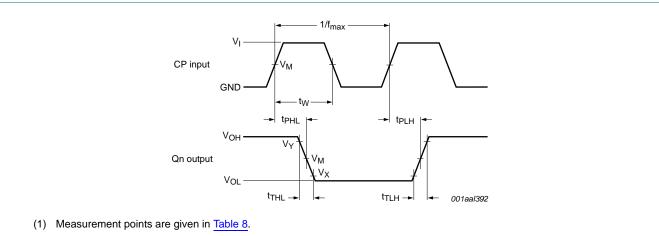
 f_o = output frequency in MHz;

 C_L = output load capacitance in pF;

 V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\sum (C_L \times V_{CC}^2 \times f_o)$ = sum of outputs.



 V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.

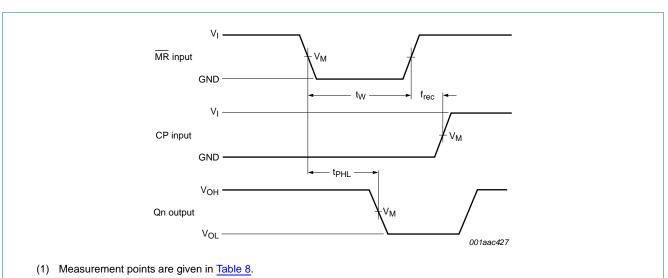
Fig 7. Waveforms showing the clock (CP) to output (Qn) propagation delays, the clock pulse width, the output transition times and the maximum clock frequency

Table 6. Weasurer	nem points							
Туре	Input	Output	Output					
	V _M	V _M	V _X	V _Y				
74HC164-Q100	0.5V _{CC}	0.5V _{CC}	0.1V _{CC}	0.9V _{CC}				
74HCT164-Q100	1.3 V	1.3 V	0.1V _{CC}	0.9V _{CC}				

Table 8.Measurement points

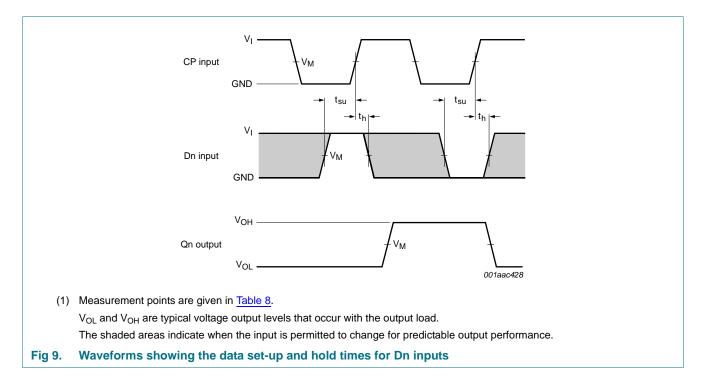
74HC164-Q100; 74HCT164-Q100

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V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.





74HC164-Q100; 74HCT164-Q100

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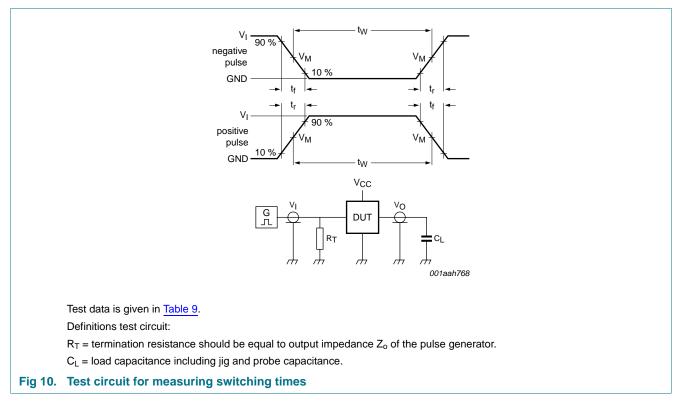


Table 9. Test data

Туре	Input	Input L		Test
	VI	t _r , t _f	CL	
74HC164-Q100	V _{CC}	6.0 ns	15 pF, 50 pF	t _{PLH} , t _{PHL}
74HCT164-Q100	3.0 V	6.0 ns	15 pF, 50 pF	t _{PLH} , t _{PHL}

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11. Package outline

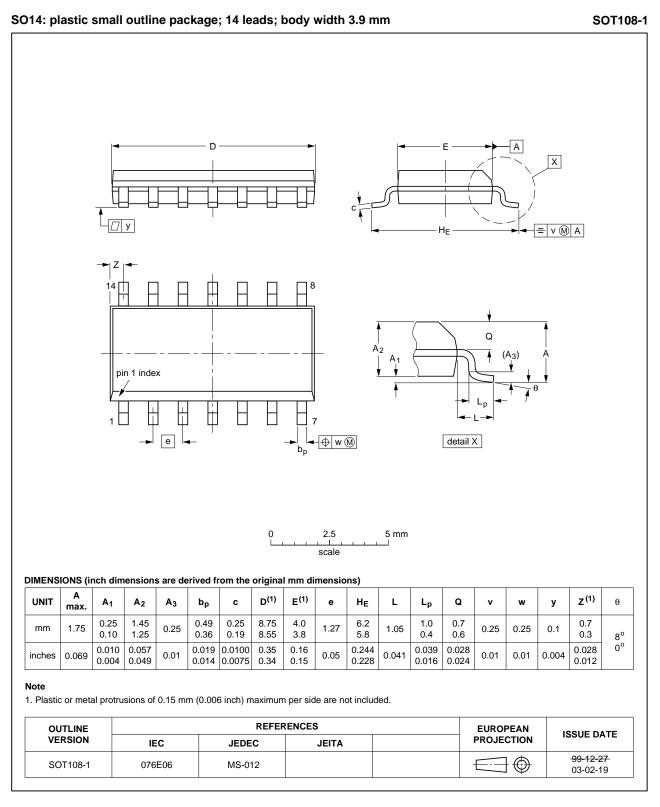


Fig 11. Package outline SOT108-1 (SO14)

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8-bit serial-in, parallel-out shift register

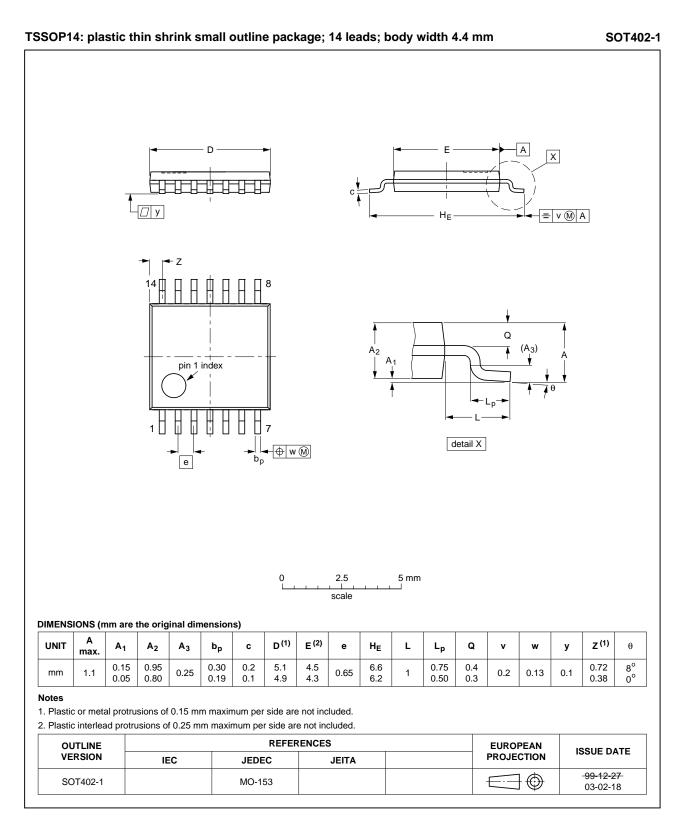
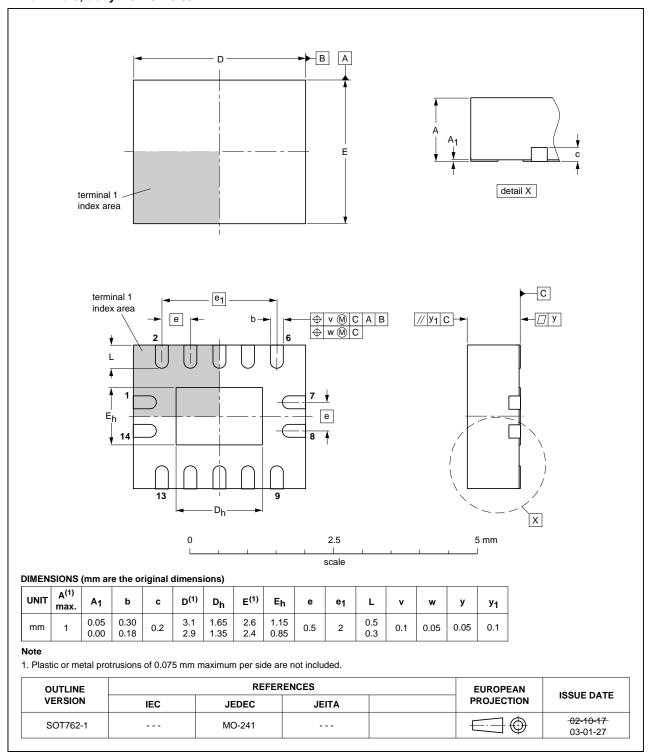


Fig 12. Package outline SOT402-1 (TSSOP14)

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DHVQFN14: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 14 terminals; body 2.5 x 3 x 0.85 mm SOT762-1

Fig 13. Package outline SOT762-1 (DHVQFN14)

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8-bit serial-in, parallel-out shift register

12. Abbreviations

Table 10. Abbreviations				
Acronym	Description			
CMOS	Complementary Metal-Oxide Semiconductor			
DUT	Device Under Test			
ESD	ElectroStatic Discharge			
HBM	Human Body Model			
MIL	Military			
MM	Machine Model			
TTL	Transistor-Transistor Logic			

13. Revision history

Table 11. Revision history	Revision history						
Document ID	Release date	Data sheet status	Change notice	Supersedes			
74HC_HCT164_Q100 v.1	20130816	Product data sheet	-	-			

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14. Legal information

14.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nexperia.com.

14.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. Nexperia does not give any

representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

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15. Contact information

For more information, please visit: http://www.nexperia.com

For sales office addresses, please send an email to: salesaddresses@nexperia.com

74HC164-Q100; 74HCT164-Q100

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